

isc N-Channel Mosfet Transistor

BUZ32

FEATURES

- 9.5A, 200V
- RDS(ON) = 0.400Ω
- SOA is Power Dissipation Limited
- · Nanosecond Switching Speeds
- · Linear Transfer Characteristics
- · High Input Impedance
- · Majority Carrier Device
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRITION

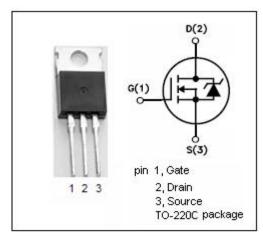
· Designed for applications such as switching regulators, switching converters, motor drivers, relay drivers, and drivers for high power bipolar switching transistors requiring high speed and low gate drive power. This type can be operated directly from integrated circuits.

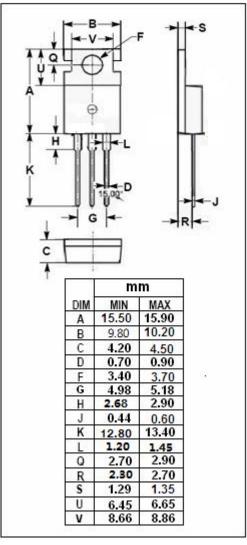


SYMBOL	ARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage (V _{GS} =0) 200		V	
V _{GS}	Gate-Source Voltage ±20		V	
I _D	Drain Current-continuous@ TC=55℃ 9.5		Α	
I _{DM}	Drain Current-Single Plused	38	Α	
P _{tot}	Total Dissipation@TC=25℃	75	W	
Tj	Max. Operating Junction Temperature 150		$^{\circ}$	
T _{stg}	Storage Temperature Range -55-		$^{\circ}$	



SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	1.67	°C/W
R _{th j-a}	R _{th j-a} Thermal Resistance,Junction to Ambient		°C/W







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =0.25mA	200			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2.1		4.0	V
V _{SD}	Diode Forward On-voltage	I _S = 19A;V _{GS} = 0			1.7	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 4.5A			0.4	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =200V; V _{GS} = 0			250	μA
Gfs	Forward Transconductance	V _{DS} = 25V; I _D =4.5A	2.2			S
t _{d(on)}	Turn-on Delay Time	V _{GS} =10V;			45	
tr	Rise Time	I _D =2.9A;			60	20
t _{d(off)}	Turn-off Delay Time	V_{DD} =30V; R_{GS} =50 Ω			140	ns
t _f	Fall Time				80	

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